Vishay Semiconductors

# Hyperfast Rectifier, 30 A FRED Pt<sup>®</sup>



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| PRIMARY CHARACTERISTICS          |                    |  |  |  |  |  |
|----------------------------------|--------------------|--|--|--|--|--|
| I <sub>F(AV)</sub>               | 30 A               |  |  |  |  |  |
| V <sub>R</sub>                   | 600 V              |  |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 1.34 V             |  |  |  |  |  |
| t <sub>rr</sub> typ.             | See Recovery table |  |  |  |  |  |
| T <sub>J</sub> max.              | 175 °C             |  |  |  |  |  |
| Package                          | TO-247AC 2L        |  |  |  |  |  |
| Circuit configuration            | Single             |  |  |  |  |  |

### **FEATURES**

- Hyperfast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current
- Single diode device
- · Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS                    |                                   |  |             |       |  |  |  |
|---|-----------------------------------|--|-------------|-------|--|--|--|
| PARAMETER                                   | SYMBOL                            | TEST CONDITIONS                                | VALUES      | UNITS |  |  |  |
| Peak repetitive reverse voltage             | V <sub>RRM</sub>                  |  | 600         | V     |  |  |  |
| Average rectified forward current           | I <sub>F(AV)</sub>                | T <sub>C</sub> = 116 °C                        | 30          | А     |  |  |  |
| Non-repetitive peak surge current           | I <sub>FSM</sub>                  | $T_{J} = 25 \text{ °C}, t_{p} = 10 \text{ ms}$ | 300         | A     |  |  |  |
| Operating junction and storage temperatures | T <sub>J</sub> , T <sub>Stg</sub> |  | -65 to +175 | °C    |  |  |  |

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                                     |  |      |      |      |       |  |
|--|-------------------------------------|--|------|------|------|-------|--|
| PARAMETER  | SYMBOL                              | TEST CONDITIONS                                      | MIN. | TYP. | MAX. | UNITS |  |
| Breakdown voltage,<br>blocking voltage   | V <sub>BR</sub> ,<br>V <sub>R</sub> | I <sub>R</sub> = 100 μA                              | 600  | -    | -    |       |  |
| Forward voltage  | N                                   | I <sub>F</sub> = 30 A                                | -    | 2.0  | 2.6  | V     |  |
| Forward voltage V <sub>F</sub>   |                                     | I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C       | -    | 1.34 | 1.75 |       |  |
| Deverse leekege eurrent  | 1                                   | $V_R = V_R$ rated                                    | -    | 0.3  | 50   |       |  |
| Reverse leakage current I <sub>R</sub>   |                                     | $T_J = 150 \ ^{\circ}C, \ V_R = V_R \ rated$         | -    | 60   | 500  | μA    |  |
| Junction capacitance   | CT                                  | V <sub>R</sub> = 600 V                               |      | 33   | -    | pF    |  |
| Series inductance  | L <sub>S</sub>                      | Measured lead to lead 5 mm from package body - 3.5 - |      | nH   |      |       |  |

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| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                 |  |   |      |      |       |    |  |
|---|-----------------|--|---|------|------|-------|----|--|
| PARAMETER   | SYMBOL          | TEST CO  | MIN.  | TYP. | MAX. | UNITS |    |  |
|   |                 | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$ |   | -    | 28   | 35    |    |  |
| Reverse recovery time t <sub>rr</sub>   |                 | T <sub>J</sub> = 25 °C   |   | -    | 31   | -     | ns |  |
|   |                 | T <sub>J</sub> = 125 °C  | I <sub>F</sub> = 30 A<br>dI <sub>F</sub> /dt = 200 A/μs | -    | 77   | -     |    |  |
| De els recessions commentes de la   | 1               | $T_J = 25 \ ^\circ C$  |   | -    | 3.5  | -     | А  |  |
| Peak recovery current I <sub>RRM</sub>  |                 | T <sub>J</sub> = 125 °C  | $V_{\rm R} = 200 \text{ A/}\mu\text{s}$                 | -    | 7.7  | -     | A  |  |
|   | Q <sub>rr</sub> | $T_J = 25 \ ^{\circ}C$   |   | -    | 65   | -     | 50 |  |
| Reverse recovery charge   |                 | T <sub>J</sub> = 125 °C  |   | -    | 345  | -     | nC |  |

| THERMAL - MECHANICAL SPECIFICATIONS                |                                   |  |              |      |            |                        |  |
|--|-----------------------------------|--|--------------|------|------------|------------------------|--|
| PARAMETER  | SYMBOL                            | TEST CONDITIONS                            | MIN.         | TYP. | MAX.       | UNITS                  |  |
| Maximum junction and storage temperature range     | T <sub>J</sub> , T <sub>Stg</sub> |  | -65          | -    | 175        | °C                     |  |
| Thermal resistance,<br>junction to case per leg    | R <sub>thJC</sub>                 |  | -            | 0.5  | 0.9        |                        |  |
| Thermal resistance,<br>junction to ambient per leg | R <sub>thJA</sub>                 | Typical socket mount                       | -            | -    | 40         | °C/W                   |  |
| Thermal resistance, case to heatsink               | R <sub>thCS</sub>                 | Mounting surface, flat, smooth and greased | -            | 0.4  | -          |                        |  |
| Weight   |                                   |  | -            | 6.0  | -          | g                      |  |
| Weight   |                                   |  | -            | 0.22 | -          | oz.                    |  |
| Mounting torque                                    |                                   |  | 6.0<br>(5.0) | -    | 12<br>(10) | kgf · cm<br>(lbf · in) |  |
| Marking device                                     |                                   | Case style TO-247AC 2L                     |              | 30EI | PH06       |                        |  |

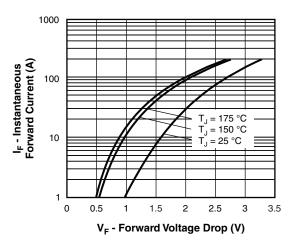


Fig. 1 - Typical Forward Voltage Drop Characteristics

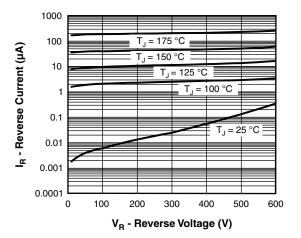


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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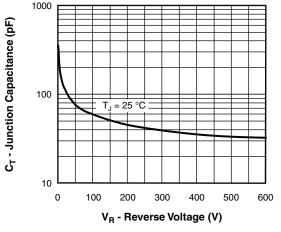


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

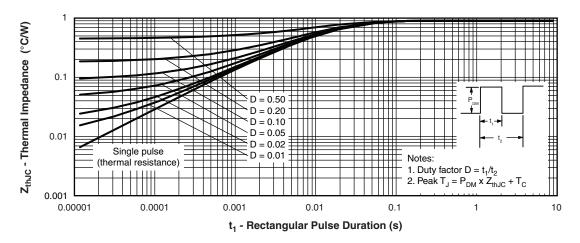
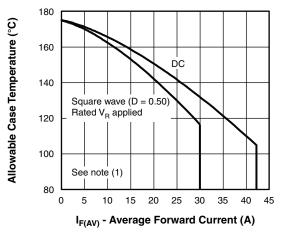
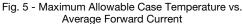


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

Average Power Loss (W)





#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} Pd = \mbox{forward power loss} = I_{F(AV)} \times V_{FM} \mbox{ at } (I_{F(AV)}/D) \mbox{ (see fig. 6);} \\ Pd_{REV} = \mbox{inverse power loss} = V_{R1} \times I_{R} \mbox{ (1 - D); } I_{R} \mbox{ at } V_{R1} = \mbox{rated } V_{R} \end{array}$ 

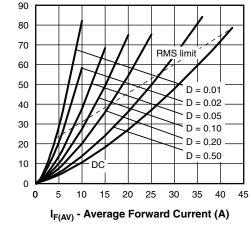


Fig. 6 - Forward Power Loss Characteristics

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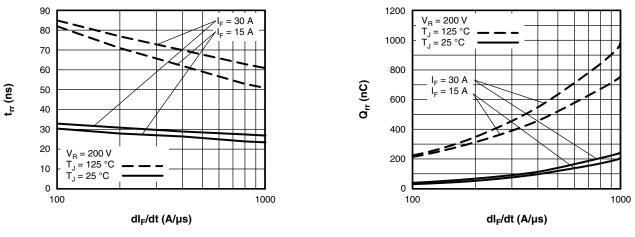


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

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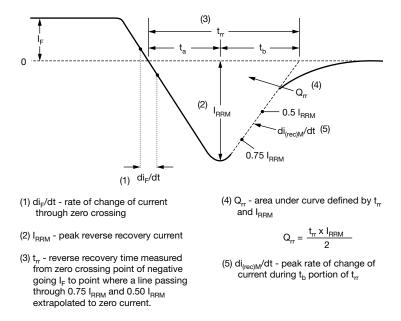


Fig. 9 - Reverse Recovery Waveform and Definitions

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### **ORDERING INFORMATION TABLE**

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| Device code | VS-    | 30     | Е               | Р                       | Н        | 06      | -N3      |
|-------------|--------|--------|-----------------|-------------------------|----------|---------|----------|
|             | 1      | 2      | 3               | 4                       | 5        | 6       | 7        |
|             | 1<br>2 |        | •               | niconduo<br>ing (30 =   | •        | oduct   |          |
|             |        | - Circ |                 | iguratio                |          |         |          |
|             | 4      |        | kage:<br>TO-247 | 7AC mo                  | dified   |         |          |
|             | 5      | - H=   | hyperfa         | ast recov               | very     |         |          |
|             | 6      | - Vol  | tage rati       | ing (06 =               | = 600 V) | )       |          |
|             | 7 -    |        |                 | ntal digit<br>jen-free, |          | complia | ant, and |

| ORDERING INFORMATION (Example) |                  |                        |                         |  |  |  |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION   |  |  |  |
| VS-30EPH06-N3                  | 25               | 500                    | Antistatic plastic tube |  |  |  |

| LINKS TO RELATED DOCUMENTS          |                          |  |  |  |  |
|-------------------------------------|--------------------------|--|--|--|--|
| Dimensions www.vishay.com/doc?96144 |                          |  |  |  |  |
| Part marking information            | www.vishay.com/doc?95648 |  |  |  |  |
| SPICE model                         | www.vishay.com/doc?96573 |  |  |  |  |

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